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With the principle of "Quality Parts, Customers Priority, Honest Operation, and Considerate Service", our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip, ALPS, ROHM, Xilinx, Pulse, ON, Everlight and Freescale. Main products comprise IC, Modules, Potentiometer, IC Socket, Relay, Connector. Our parts cover such applications as commercial, industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!



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Silicon PIN Diode

- Current-controlled RF resistor for switching and attenuating applications
- Frequency range 1 MHz ... 2 GHz
- Especially useful as antenna switch in TV-sat tuners
- Very low harmonics
- Pb-free (RoHS compliant) package 1)
- Qualified according AEC Q101





BA779



Туре	Package	Configuration	L _S (nH)	Marking
BA779	SOT 23	single	1.8	PA

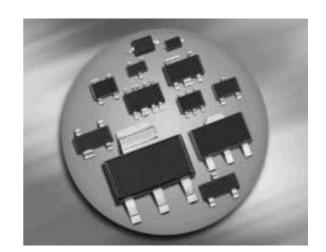
Maximum Ratings at $T_A = 25$ °C, unless otherwise specified

	· · ·		
Parameter	Symbol	Value	Unit
Diode reverse voltage	V_{R}	50	V
Forward current	I _F	50	mA
Junction temperature	T _i	150	°C
Operating temperature range	T_{op}	-55 125	
Storage temperature	$T_{\rm stg}$	-55 150	

Thermal Resistance

Parameter	Symbol	Value	Unit
Junction - soldering point ²⁾	R _{thJS}	≤ 370	K/W

¹Pb-containing package may be available upon special request



 $^{^2\}mbox{For calculation of }R_{\mbox{\scriptsize thJA}}$ please refer to Application Note Thermal Resistance



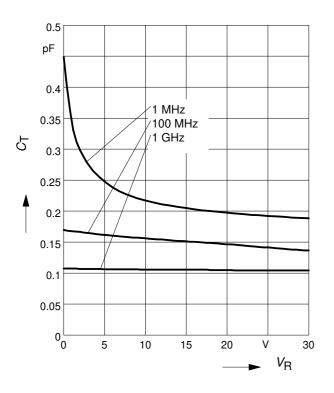
Electrical Characteristics at $T_A = 25$ °C, unless otherwise specified

Parameter	Symbol	Values			Unit
		min.	typ.	max.	
DC Characteristics	•				
Reverse current	I _R	-	-	20	nA
$V_{R} = 30 \text{ V}$					
Forward voltage	V_{F}	-	-	1.1	V
$I_{\text{F}} = 50 \text{ mA}$					
AC Characteristics					
Diode capacitance	C _T				pF
$V_{R} = 0 \text{ V}, f = 100 \text{ MHz}$		-	0.26	0.4	
$V_{R} = 10 \text{ V}, f = 1 \text{ MHz}$		-	0.22	0.6	
Reverse parallel resistance	R_{P}				kΩ
$V_{R} = 1 \text{ V}, f = 100 \text{ MHz}$		-	50	-	
$V_{R} = 0 \text{ V}, f = 1 \text{ GHz}$		-	10	-	
Forward resistance	r_{f}				Ω
$I_{\text{F}} = 1.5 \text{ mA}, f = 100 \text{ MHz}$		-	22	40	
$I_{\rm F} = 10 \text{ mA}, f = 100 \text{ MHz}$		-	4.5	7	
Charge carrier life time	τ _{rr}	-	1600	-	nS
$I_F = 10 \text{ mA}$, $I_R = 6 \text{ mA}$, measured at $I_R = 3 \text{ mA}$,					
$R_{L} = 100 \ \Omega$					
I-region width	$ W_{\rm l} $	-	130	-	μm



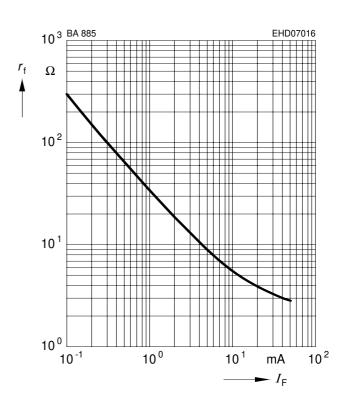
Diode capacitance $C_T = f(V_R)$

f = 1MHz

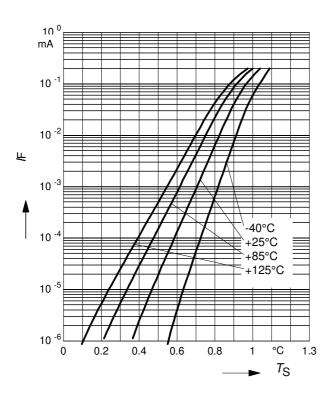


Forward resistance $r_f = f(I_F)$

f = 1MHz



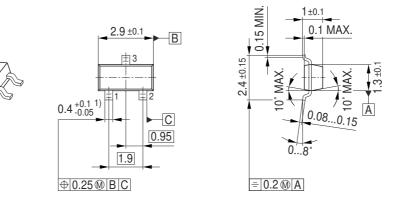
Forward current $I_F = f(V_F)$



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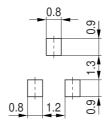


Package Outline

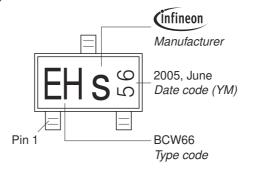


1) Lead width can be 0.6 max. in dambar area

Foot Print

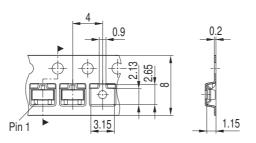


Marking Layout (Example)



Standard Packing

Reel ø180 mm = 3.000 Pieces/Reel Reel ø330 mm = 10.000 Pieces/Reel



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